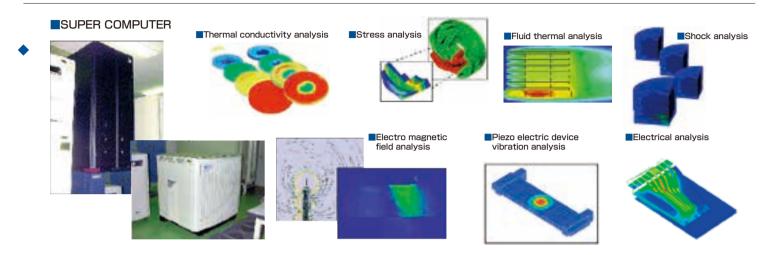


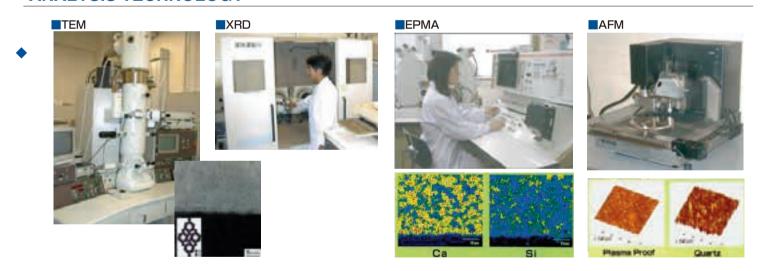
Ceramic Components for Semiconductor Processing

# **TECHNOLOGY**

## **DESIGN & SIMULATION TECHNOLOGY**



## **ANALYSIS TECHNOLOGY**



## **EVALUATION TECHNOLOGY**



# MATERIAL CHARACTERISTICS

Material Item		Unit	Measuring Method			Sapphire				
Kyocera No.				A-479 A-479SS		A-479M A-479G	A-480S A-601D A-601L		SA-100	
Color				99% White	99.5% Ivory	99.5% Ivory	99.7% Ivory	99.9% Ivory	99.9% Transparent	
Bulk Density		g/cm <sup>3</sup>	JIS R1634	3.8	3.9	3.9	3.9	3.9	3.97	
Water Absorption		%	JIS R1634	0	0	0	0	0	0	
Vickers Hardness HV1 (Load=9.807N)		(GPa)	JIS R1610	15.2	16.0	15.7	17.2	17.5	22.5	
Flexural Strength (3PB) R.T.		MPa	JIS R1601	310	360	370	380	400	690	
Young's Modulus of Elas	Young's Modulus of Elasticity		JIS R1602	360	370	370	380	380	470	
Poisson's Ratio	Poisson's Ratio		JIS N 1002	0.23	0.23	0.23	0.23	0.23	-	
Fracture Toughness (	Fracture Toughness (SEPB)		JIS R1607	3~4	4	-	-	5 ~ 6	-	
Coefficient of Linear Thermal Expansion	40℃~ 400℃	x10 <sup>-6</sup> /°C	JIS R1618	7.2	7.2	7.2	7.2	7.2	Parallel to C-axis	7.7
	40℃~800℃	X10 / C		8.0	8.0	8.0	8.0	8.0	Vertical to C-axis	7.0
Thermal Conductivity 20°C		W/(m.K)	JIS R1611	29	32	32	32	34	41	
Specific Heat Capacity		J/(g·K)	JIS R1611	0.79	0.78	0.78	0.79	0.78	0.75	
Heat Shock Resistance		$^{\circ}$	JIS R1648	200	250	-	-	-	-	
Dielectric Strength		KV/mm		15	15	15	15	15	48	
	20℃			>1014	>1014	>1014	>1014	>1014	>10 <sup>14</sup>	
Volume Resistivity	300℃	Ω .cm		10 <sup>10</sup>	10 <sup>13</sup>	10 <sup>13</sup>	10 <sup>13</sup>	10 <sup>13</sup>	-	
	500℃		JIS	10 <sup>8</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>11</sup>	
Dielectric Constant (1MHz)		_	C2141	9.9	9.9	9.9	9.9	9.9	Parallel to C-axis	_
			02141	5.5	5.5				Vertical to C-axis	9.3
Dielectric Loss Angle (1MHz)		(X10 <sup>4</sup> )		2	1	1	1	1	<1	
Loss Factor		(X10 <sup>4</sup> )		20	10	10	10	10	-	
Nitric Acid(60%)90°C	WT Loss	JIS	0.10	0.07	-	0.05	0.03	÷ 0.00		
Sulphuric Acid(95%)95°C			0.33	0.25	-	0.22	0.19	<b>÷</b> 0.00		
Caustic Soda(30%)80℃	mg/cm <sup>2</sup>	R1614	0.26	0.05	-	0.04	0.03	<b>÷</b> 0.00		

Item	Material	Unit	Measuring Method			Nitride <sub>8</sub> N <sub>4</sub> )			Carbide iC)	Alum Niti (A	ide		lierite L <sub>2</sub> O <sub>3</sub> · 5SiO <sub>2</sub> )	Yttria (Y <sub>2</sub> O <sub>2</sub> )	Zirconia (ZrO <sub>2</sub> )
Kyocera No.				SN-201B	SN-260	SN-240	SN-241	SC-211	SC1000	AN216A	AN2000	CO-220	CO-720	Y0100A	Z-201N
Color				Black	Black	Black	Black	Black	Black	Gray	Ivory	Gray	Gray	White	Ivory
Bulk Density		g/cm <sup>3</sup>	JIS R1634	3.2	3.1	3.3	3.2	$3.2 \times 10^{3}$	3.16	3.4	3.2	2.5	2.5	4.9	6.0
Water Absorption		%	JIS R1634	0	0	0	0	0	0	0	0	0	0	0	0
Vickers Hardness HV1 (I	Load=9.807N)	(GPa)	JIS R1610	13.9	12.7	14.0	13.8	22.0	23.0	10.4	11.2	8	8.5	6.0	12.3
Flexural Strength (3P	B) R.T.	MPa	JIS R1601	580	900	1,020	790	540	450	310	220	190	200	130	1,000
Young's Modulus of Elas	sticity	GPa	JIS R1602	290	270	300	290	430	440	320	310	140	145	160	200
Poisson's Ratio		-	JIS N 1002	0.28	0.28	0.28	0.28	0.16	0.17	0.24	0.24	0.31	0.31	-	0.31
Fracture Toughness (	SEPB)	MPam <sup>1/2</sup>	JIS R1607	4~5	6 ~ 7	7	6 ~ 7	4~5	2~3	-	-	1 ~ 1.5	1 ~ 1.5	1.1	4~5
Coefficient of Linear	40℃~400℃	x10 <sup>-6</sup> /°C	JIS R1618	2.4	2.8	2.8	2.9	3.7	3.7	4.6	4.6	l/	1.5(40°C~ 400°C) 2.1(40°C~ 800°C)	7.2	10.5
Thermal Expansion	40℃~800℃	X10 / C	313 111010	3.2	3.4	3.3	3.5	4.4	4.4	5.3	5.2	< 0.05 (23°C) < 0.02 (22°C)	< 0.05 (23°C)   < 0.02 (22°C)	7.6	11.0
Thermal Conductivity 20	)℃	W/(m·K)	JIS R1611	25	23	27	54	60	200	150	67	4	4	14	3
Specific Heat Capacity		J/(g·K)	JIS R1611	0.64	0.66	0.65	0.66	0.67	0.67	0.71	0.72	0.71	-	0.45	0.46
Heat Shock Resistance		℃	JIS R1648	550	800	800	900	400	-	-	-	-	400	-	300
Dielectric Strength		KV/mm		-	12	13	12	-	-	14	16	19.1	19.3	11	11
	20℃			>1014	>1014	>1014	>1014	10⁵	10 <sup>8</sup>	>1014	>1014	>1014	>1014	>10 <sup>13</sup>	10 <sup>13</sup>
Volume Resistivity	300℃	Ω .cm		10 <sup>12</sup>	10 <sup>13</sup>	10 <sup>12</sup>	10 <sup>12</sup>	10 <sup>4</sup>	10 <sup>4</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>12</sup>	10 <sup>12</sup>	10 <sup>10</sup>	10 <sup>6</sup>
	500℃		JIS	10 <sup>10</sup>	10 <sup>11</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>3</sup>	10 <sup>3</sup>	10 <sup>8</sup>	10 <sup>9</sup>	10 <sup>10</sup>	10 <sup>10</sup>	10 <sup>7</sup>	10 <sup>3</sup>
Dielectric Constant (1M	Hz)	-	C2141	-	8.3	9.6	9.6	-	-	8.6	8.5	4.9	4.9	11.0	33.0
Dielectric Loss Angle (1	IMHz)	(X10 <sup>4</sup> )		-	5	19	18	-	-	3	2	9	8.5	5	16
Loss Factor		(X10 <sup>4</sup> )		-	-	-	-	-	-	26	17	-	-	55	520
24, ℃9(%00)Nitric Acid	Н	WT Loss	JIS	-	1.02	1.11	0.18	0.04	⇒ 0.00	-	-	-	-	-	<b>⇒</b> 0.00
Sulphuric Acid(95%)95°C	,24H		R1614	-	0.01	0	0	0.01	⇒ 0.00	-	-	-	-	-	0.04
Caustic Soda(30%)80℃	,24H	mg/cm <sup>2</sup>	n1014	-	0.49	0.22	0.07	⇒ 0.00	⇒ 0.00	-	-	-	-	-	0.08

# **Unit Conversion Table**

#### **Stress**

Мра	Kgf/mm <sup>2</sup>	Kgf/cm <sup>2</sup>			
1	$1.0197 \times 10^{-1}$	1.0197 × 10			
9.807	1	1 × 10 <sup>2</sup>			
$9.807 \times 10^{-2}$	1 × 10 <sup>-2</sup>	1			

## **Thermal Conductivity**

W/(m · K)	Cal/cm · Sec · °C
1	$2.39 \times 10^{-3}$
1.163	2.78 × 10 <sup>-3</sup>
418.7	1

## Notes

- These values are only for reference, showing the measurement results of test pieces specified.
- The values may change dependent on the using conditions and the shape of products.
- For more details, please feel free to contact us.

# KYOCERa

# WAFER MANUFACTURING PROCESS



## **Alumina Wafer Polishing Plate / Turn Table**

- Material : Al<sub>2</sub>O<sub>3</sub>

Size : Up to 39" in diameter

Features : •High rigidity

High chemical durability

•Surface shape & roughness control



## **Silicon Carbide Wafer Polishing Plate**

Material : SiC

Size : Up to 30" in diameter

- Features : •High thermal conductivity

•Low thermal expansion

High rigidity



## **Pad Dresser**

- Material : Al<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>

- Features : •High wear resistance

Square bumps / pyramid bumps



## **Sapphire Carrier Plate**

Material : Sapphire

Size : Up to 8" in diameter

- Features : • High purity

High chemical durability

No grain boundary

Transparent

# **DEVICE MANUFACTURING PROCESS**



## **Plasma Proof Dome**

- Material : Al<sub>2</sub>O<sub>3</sub>

- Size : For 200mm / 300mm equipment

Features : •High purity

High plasma durability



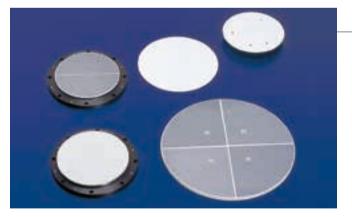
## **Plasma Proof Ring**

- Material : Al<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>

- Size : For 200mm / 300mm equipment

- Features : •High purity

High plasma durability



## **Electro-Static Chuck**

- Material : Al<sub>2</sub>O<sub>3</sub>, AlN, Sapphire

Size : For 200mm / 300mm equipment

- Features : ●High purity

•High plasma durability

Good chucking / de-chucking response

•High temp. and low temp. application



## Heater

Material : AIN

Size: For 200mm / 300mm equipment

- Features : ●High purity

High plasma durability

•Uniform thermal distribution

# **DEVICE MANUFACTURING PROCESS**



## **Vacuum Chuck**

- Material : Al<sub>2</sub>O<sub>3</sub>, Porous Al<sub>2</sub>O<sub>3</sub>, SiC

Size: For 200mm / 300mm equipment

- Features : ●High purity

High chemical durabilityVacuum channel inside

Variety surface shape



## Nozzle

- Material : Al<sub>2</sub>O<sub>3</sub>

- Size : Nozzle diameter +/-5μm - Features : •High plasma durability

•Gas flow rate control



## **End Effector**

- Material : Al₂O₃, SiC, Sapphire

Size: For 200mm / 300mm equipment

- Features : ●High purity

•Vacuum channel inside

SiC coating

Mirror polished surface



## **Chamber Window & Tube**

Material : Sapphire

Features : •High purity

•High plasma durability

Transparent

•High transmission factor

# **EPOCH-MAKING TECHNOLOGIES**



## **USM Stage - Assembly Technology**

- Material : Al<sub>2</sub>O<sub>3</sub>, Al

Non Magnetic Metal, etc.

Features : •Ultrasonic Motor drive

High positioning accuracy

Compact design



## **Metalized Products - Metal Assembly Technology**

- Material : Al<sub>2</sub>O<sub>3</sub>, Al, Stainless steel, etc.

- Application: •IC Packages

High vacuum componentHigh voltage terminal, etc.

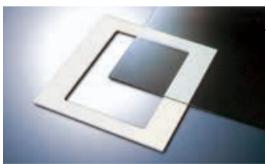


## **Coating Technology**

- Material : SiC, DLC, etc.

Features : •Discharge of static electricity

Soft contact



## **Large Size Product Manufacturing Technology**

- Material : Al<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, SiC, Si<sub>3</sub>N<sub>4</sub>

Application : •LCD manufacturing equipment

Lithography equipment



## **Material Development Technology**

## example

├ Material : Low thermal expansion materials

- Application: •Lithography equipment

Wafer Inspection equipment



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